# **16-BIT BUS SWITCH**

2B4

### FEATURES:

- · Bus switches provide zero delay paths
- Low switch on-resistance
- TTL-compatible input and output levels
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- · Hot insertion capability
- · Very low power dissipation
- Available in TSSOP package

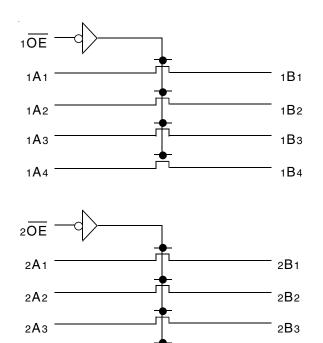
# DESCRIPTION:

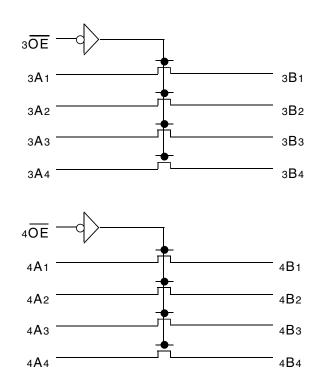
The FST163244 belongs to IDT's family of Bus switches. Bus switch devices perform the function of connecting or isolating two ports without providing any inherent current sink or source capability. They generate little or no noise of their own while providing a low resistance path for an external driver. These devices connect input and output ports through an n-channel FET. When the gate-to-source junction of this FET is adequately forward-biased, the device conducts and the resistance between input and output ports is small. Without adequate bias on the gate-to-source junction of the FET, the FET is turned off, therefore with no VCC applied, the device has hot insertion capability.

The low on-resistance and simplicity of the connection between input and output ports reduces the delay in this path to close to zero.

The FST163244 is pin-compatible with and functionally similar to the FCT16244T.

# FUNCTIONAL BLOCK DIAGRAM





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### **PIN CONFIGURATION**

		ι Γ		1	
1 <mark>0E</mark>	1	$\bigcirc$	48		20E
1B1	2		47		1 <b>A</b> 1
1B2	3		46		1 <b>A</b> 2
GND	4		45		GND
1 <b>B</b> 3	5		44		1 <b>A</b> 3
1B4	6		43		1 <b>A</b> 4
Vcc	7		42		Vcc
2B1	8		41		2 <b>A</b> 1
2B2	9		40		2 <b>A</b> 2
GND	10		39		GND
2B3	11		38		2 <b>A</b> 3
2B4	12		37		2 <b>A</b> 4
3B1	13		36		3 <b>A</b> 1
3 <b>B</b> 2	14		35		3 <b>A</b> 2
GND	15		34		GND
зВз	16		33		зАз
3 <b>B</b> 4	17		32		3 <b>A</b> 4
Vcc	18		31		Vcc
4B1	19		30		4 <b>A</b> 1
4B2	20		29		4 <b>A</b> 2
GND	21		28		GND
4 <b>B</b> 3	22		27		4 <b>A</b> 3
4B4	23		26		4 <b>A</b> 4
4 <mark>0E</mark>	24		25		з <mark>ОЕ</mark>

TSSOP TOP VIEW

#### NDUSTRIAL TEMPERATURE RANGE

# ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	Terminal Voltage with Respect to GND	-0.5 to +7	V
TSTG	Storage Temperature	-65 to +150	°C
Ιουτ	Maximum Continuous Channel Current	128	mA

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc, Control, and Switch terminals.

### CAPACITANCE<sup>(1)</sup>

Symbol	Parameter	Conditions <sup>(2)</sup>	Тур.	Unit
CIN	Control Input Capacitance		6	рF
CI/O	Switch Input/Output Capacitance	Switch Off	12	pF

NOTES:

1. Capacitance is characterized but not tested.

2.  $T_A = 25^{\circ}C$ , f = 1MHz,  $V_{IN} = 0V$ ,  $V_{OUT} = 0V$ .

### **PIN DESCRIPTION**

Pin Names	Description
xŌĒ	Output Enable Inputs (Active LOW)
xAx	A Port Bits
xBx	B Port Bits

# FUNCTION TABLE<sup>(1)</sup>

Inputs	
xOE	Outputs
L	Connect A to B
Н	Disconnect A from B

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

# DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: TA =  $-40^{\circ}$ C to  $+85^{\circ}$ C, VCC = 5.0V  $\pm 10\%$ 

Symbol	Parameter	Test Conditions <sup>(1)</sup>		Min.	Typ. <sup>(2)</sup>	Max.	Unit
Vih	Control Input HIGH Voltage	Guaranteed Logic HIGH for Con	trol Inputs	2	_		V
VIL	Control Input LOW Voltage	Guaranteed Logic LOW for Cont	rol Inputs	_	—	0.8	V
Ін	Control Input HIGH Current	Vcc = Max.	VI = VCC	_	—	±1	μA
lı.	Control Input LOW Current	]	VI = GND	_	—	±1	
Іоzн	Current During	Vcc = Max., Vo = 0 to 5V		_	—	±1	μA
Iozl	Bus Switch Disconnect			—	—	±1	
Vik	Clamp Diode Voltage	Vcc = Min., IIN = -18mA		_	-0.7	-1.2	V
IOFF	Switch Power Off Leakage	Vcc = 0V, VIN or Vo $\leq 5.5V$		_	—	±1	μA
Icc	Quiescent Power Supply Current	Vcc = Max., VIN = GND or Vcc	;	_	0.1	3	μA

# BUS SWITCH IMPEDANCE OVER OPERATING RANGE

 $\label{eq:Following} Following \mbox{ Conditions } \mbox{ Apply } \mbox{ Unless } \mbox{ Otherwise } \mbox{ Specified:} \\$ 

Industrial: TA =  $-40^{\circ}$ C to  $+85^{\circ}$ C, VCC =  $5.0V \pm 10\%$ 

Symbol	Parameter	Test Conditions	Min.	Typ. <sup>(1)</sup>	Max.	Unit
Ron	Switch On Resistance, A to B <sup>(2)</sup>	Vcc = Min., $Vin = 0V$ , $Ion = 12mA$	—	5	7	Ω
		Vcc = Min., $VIN = 2.4V$ , $ION = 8mA$	—	10	15	
los	Short Circuit Current, A to B <sup>(3)</sup>	A(B) = 0V, B(A) = Vcc	100	—	—	mA

NOTES:

1. Typical values are at Vcc = 5.0V, +25°C ambient.

2. The voltage drop between the indicated ports divided by the current through the switch.

3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.

# POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditi	ons <sup>(1)</sup>	Min.	Typ. <sup>(2)</sup>	Max.	Unit
∆lcc	Quiescent Power Supply Current TTL Inputs HIGH	Vcc = Max. $VIN = 3.4V^{(3)}$		-	0.5	1.5	mA
ICCD	Dynamic Power Supply Current <sup>(4,5)</sup>	Vcc = Max. One Enable Pin Toggling 50% Duty Cycle	VIN = VCC VIN = GND	Ι	120	160	μΑ/ MHz/ Enable
lc	Total Power Supply Current <sup>(6)</sup>	Vcc = Max. One Enable Pin Toggling	VIN = VCC VIN = GND	-	1.2	1.6	mA
		fi = 10MHz 50% Duty Cycle	VIN = VCC VIN = 3.4V	—	1.5	2.4	
		Vcc = Max. Four Enable Pins Toggling	VIN = VCC VIN = GND	-	4.8	6.4	
		fi = 10MHz 50% Duty Cycle	VIN = VCC VIN = 3.4V	_	5.8	9.4	

#### NOTES:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type. TA = -40°C to +85°C

2. Typical values are at Vcc = 5.0V, +25°C ambient.

3. Per TTL driven input (VIN = 3.4V). All other inputs at Vcc or GND. Switch inputs do not contribute to ∆Icc.

4. This parameter represents the current required to switch the internal capacitance of the control inputs at the specified frequency.

Switch inputs generate no significant power supply currents as they transition. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations. 5. CPD = IccD/Vcc

CPD = Power Dissipation Capacitance

- 6. IC = IQUIESCENT + INPUTS + IDYNAMIC
- $IC = ICC + \Delta ICC DHNT + ICCD (fiN)$

Icc = Quiescent Current

 $\Delta$ Icc = Power Supply Current for a TTL High Input (VIN = 3.4V)

DH = Duty Cycle for TTL Inputs High

NT = Number of TTL Inputs at DH

ICCD = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

fi = Control Input Frequency

N = Number of Control Inputs Toggling at fi

# SWITCHING CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: TA =  $-40^{\circ}$ C to  $+85^{\circ}$ C, VCC =  $5.0V \pm 10\%$ 

			Vcc = 5V ± 10%	D	Vcc = 4V	
Symbol	Description <sup>(1)</sup>	Min.	Тур.	Max.	Max.	Unit
<b>t</b> PLH	Data Propagation Delay	—	—	0.25	0.25	ns
<b>t</b> PHL	A to B, B to A <sup>(2)</sup>					
tрzн	Switch CONNECT Delay	1.5	—	5.6	—	ns
tpzL.	xOE to A or B					
<b>t</b> PHZ	Switch DISCONNECT Delay	1.5	—	5.2	—	ns
<b>t</b> PLZ	xOE to A or B					
lQcıl	Charge Injection During Switch DISCONNECT	—	1.5	—	_	рС
	$x\overline{OE}$ to A or B <sup>(3)</sup>					

### NOTES:

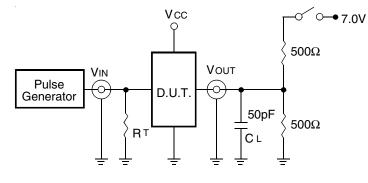
1. See test circuits and waveforms.

2. The bus switch contributes no Propagation Delay other than the RC Delay of the load interacting with the RC of the switch.

3. |Qcil is the charge injection for a single switch DISCONNECT and applies to either single switches or multiplexers. Charge injection is reduced because the injection from the DISCONNECT of the first path is compensated by the CONNECT of the second path.

#### **INDUSTRIAL TEMPERATURE RANGE**

# TEST CIRCUITS AND WAVEFORMS



### Test Circuits for All Outputs

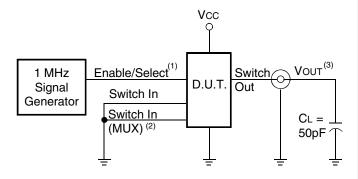
### SWITCH POSITION

Test	Switch
Open Drain	
Disable Low	Closed
Enable Low	
All Other Tests	Open

#### **DEFINITIONS:**

CL = Load capacitance: includes jig and probe capacitance.

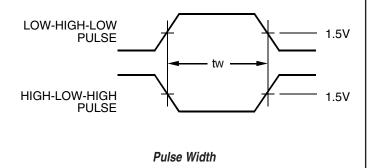
RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

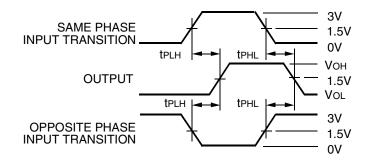


### Charge Injection

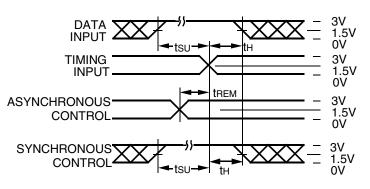
#### NOTES:

- Select is used with multiplexers for measuring IQDCII during multiplexer select. During all other tests Enable is used.
- 2. Used with multiplexers to measure IQDCII only.
- 3. Charge Injection =  $\Delta$ VouT CL, with Enable toggling for IQcII or Select toggling for IQpcII.  $\Delta$ VouT is the change in VouT and is measured with a 10M $\Omega$  probe.

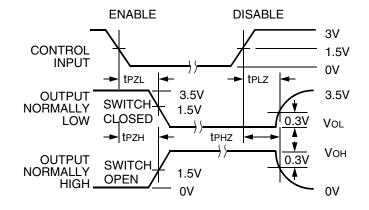




#### **Propagation Delay**



Set-up, Hold, and Release Times

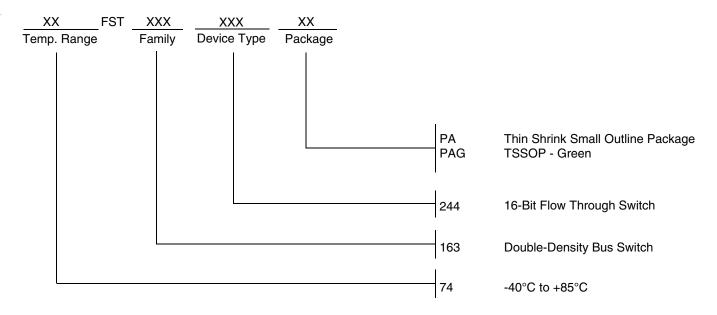


### Enable and Disable Times

#### NOTES:

- 1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
- 2. Pulse Generator for All Pulses: Rate  $\leq$  1.0MHz; tF  $\leq$  2.5ns; tR  $\leq$  2.5ns.

# **ORDERING INFORMATION**





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### for SALES:

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